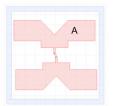
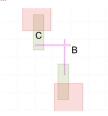
Sunday, 7 May 2023 09.39

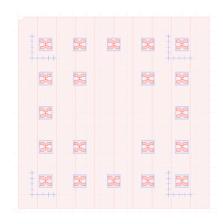
Device Design

- 3 Fabrication Steps:
 A) Pads red
 B) Manhattan JJ purple
 - C) Patches green

20 identical Devices each Chip (7mm x 7mm) - 300nm electrode widfth







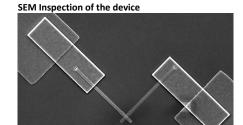
Here is a recipe only to produce cross-type Jospehson Junctions using two stacked resists (and a single exposure)

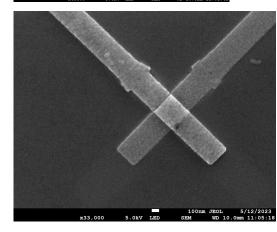
Pads

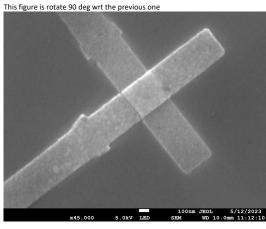
Operation	Description	Tool	Comment	Inspection
Clean	1,3 Dioxilane - 10 min			
	Acetone -5 min			
	IPA -1 min			
Pre-Bake	185C – 120s			
Spin	PMMA A4 spin (vent hole closed) 90 s@4.0krpm, (film ≈ 300 nm)			
Bake	120 s bake, 185 ⋅ C			
Expose	Base dose $1000 \frac{\mu C}{cm2}$	10nA		
Ash	45 s			
Develop	MIBK: IPA 1: 3 - 60s + IPA 10 s			
Evaporate	$\theta = 0$, 1.0 A/s, 100nm			
Lift Off	Acetone Overnight (or 3 h)			

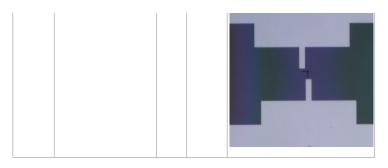
Junctions

Operation	Description	Tool	Comment	Inspection
Clean	1,3 Dioxilane - 10 min			
	Acetone -5 min			
	IPA -1 min			
Pre-Bake	185C – 120s			
Spin	MMA EL 13 spin (vent hole closed) 90 s@5.0krpm, (film ≈ 350 nm)			
Bake	90 s bake, 185 ⋅ C			
Spin	CSAR 960 s@2.0krpm (film ≈ 300 nm)			
Bake	90 s bake 185 · C			
Expose	Base dose –825μC/cm2	1nA		









Develop	n-Amyl- 60s + IPA 15 s; th MIBK: IPA 1:3 - 75s + IPA 15 s	erAsh 30 s at the End	
Evaporate	$\theta = 42,1.6 \text{ A/s}, 45 \text{ nm}$		
	$\theta = 42,1.6 \text{ A/s}, 65 \text{ nm}$		
Lift Off	Acetone Overnight (or 3 h)		78

Patches

Operation	Description	Tool	Comment	Inspection
Clean	1,3 Dioxilane - 10 min			
	Acetone -5 min			
	IPA -1 min			
Pre-Bake	185C – 120s			
Spin	PMMA A4 spin (vent hole closed) 60 s@4.0krpm, (film ≈ 300 nm)			
Bake	120 s bake 185 ⋅ C			
Expose	Base dose 1000 μ C/cm2	3nA		
Ash	45 s			
Develop	MIBK: IPA 1: 3 - 60s + IPA 10 s			
Mill	500V 27mA Acc V= 90 T= 3.30min Tilt =30			
Evaporate	$\theta = 0, \frac{1.0 \text{ A}}{\text{s}}, 140 \text{nm}$			
Lift Off	Acetone Overnight (or 3 h)			